

TOSHIBA Photocoupler Photorelay

TLX9150M

1. Description

Toshiba TLX9150M consists of an infrared emitting diode optically coupled to a photo-MOSFET in a SO12L-T package.

This coupler uses high voltage MOSFET between output terminals, making it suitable for battery-related control applications.

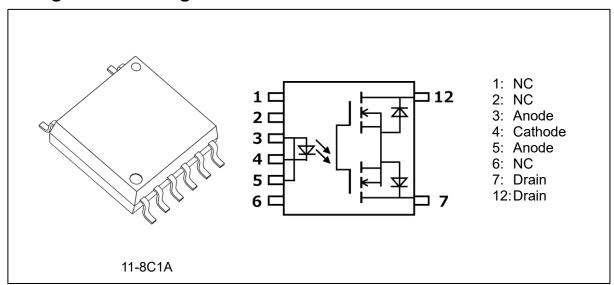
2. Applications

- Battery Control in Automotive Equipment
- Fuel Battery Control in Automotive Equipment
- Application for Electrical Vehicle

3. Features

- Normally open (1-Form-A) device
- Peak off-state voltage: 900 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 50 mA (max)
- On-state resistance: 250Ω (max)(@t < 1s)
- Isolation voltage: 5000 Vrms (min)
- Clearance distance: 8 mm (min)
- Creepage distance: 8 mm (min)
- Insulation thickness: 0.4 mm (min)
- Outer resin: CTI > 600
- AEC-Q101 qualified

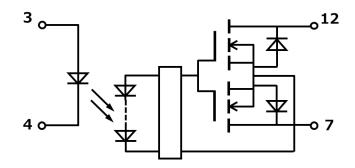
4. Packing and Pin Assignments



Start of commercial production 2024-09



5. Internal Circuit





6. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

	Characteri	stics	Symbol	Note	Rating	Unit
LED	Forward current		l _F		30	mA
	Forward current derating (T _a ≥	ΔI _F /°C		-0.8	mA/°C	
	Reverse voltage	V _R		5	V	
	Input Power Dissipation	P _D		50	mW	
	Input Power Dissipation Deratir	ng (Ta ≥ 100 °C)	ΔP _D /°C		-1.3	mW/°C
	Junction temperature		Tj		135	°C
Detector		T _a = 25 °C			50	mA
	On-state current	T _a = 105 °C	Ion		20	mA
		T _a = 125 °C			10	mA
	On-state current derating	T _a ≥ 45 °C	ΔI _{ON} /°C		-0.5	mA/°C
		T _a = 25 °C		(Note 1)	150	mA
	On-state current (Peak)	T _a = 105 °C	lonpk		60	mA
		T _a = 125 °C			30	mA
	Avalanche current		IAV	(Note 2)	0.6	mA
	Output power dissipation		Po		600	mW
	Output power dissipation derati	ing (Ta ≥ 47°C)	ΔPo/°C		-7	mW/°C
	Junction temperature		Tj		135	°C
Common	Storage temperature	orage temperature			-55 to 150	°C
	Operating temperature		Topr		-40 to 125	°C
	Lead soldering temperature (10	T _{sol}		260	°C	
	Isolation voltage (AC, 60 s, R.F	H. ≤ 60%)	BVs	(Note 3)	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note: This product is more sensitive than conventional products to electrostatic discharge (ESD). It is therefore all the more necessary to observe general precautions regarding ESD when handling this

Note 1: Exponential curve, pulse width < 1ms, f ≤ 150Hz

Note 2: 1min (max continuous), Duty cycle=0.1%, 5 time over lifetime.

Note 3: LED pins are shorted together. Detector pins are also shorted together.



7. Recommended Operating Conditions (Note)

Characteristics	Symbol		Тур.	Max	Unit
Supply voltage	V_{DD}	_	_	720	V
Forward current	l _F	5	10	20	mA
On-state current	Ion	_	_	50	mA
Operating temperature	T_{opr}	-40	_	125	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

8. Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage		I _F = 10 mA	1.5	1.65	1.8	.,
		VF	$I_F = 10 \text{ mA}, T_a = -40 \text{ to } 125^{\circ}\text{C}$	1.4	1	1.95	V
	Reverse current	I _R	V _R = 5 V	1	1	10	μΑ
	Capacitance	Ст	V = 0 V, f = 1MHz	1	45	l	pF
Detector	Output withstand voltage	Voff	I _{OFF} = 10 μA, T _a = 25 °C	900	1	1	V
	Off-state current		V _{OFF} = 900 V, T _a = 25 °C	1	l	100	
		I _{OFF}	V _{OFF} = 900 V, T _a = -40 to 105 °C	1	l	1000	nA
			V _{OFF} = 900 V, T _a = -40 to 125 °C			5000	
	Capacitance	C _{OFF}	V = 0 V, f = 1 MHz	_	60	_	pF

9. Coupled Electrical Characteristics

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current		I _{ON} = 50 mA, T _a = 25°C, t = 10 ms	_	_	3	
	I _{FT}	I _{ON} = 20 mA, T _a = -40 to 105°C, t = 10 ms	_	_	3	mA
		I _{ON} = 10 mA, T _a = -40 to 125°C, t = 10 ms — —		_	3	
Return LED current	IFC	I _{OFF} = 100 μA, T _a = -40 to 125°C, t = 40 ms	0.05	_	1	mA
On-state resistance		I_{ON} = 50 mA, I_F = 10 mA, T_a = 25°C, t < 1 s	_	_	250	
	Ron $I_{ON} = 20 \text{ mA}, I_F = 10 \text{ mA},$ $T_a = -40 \text{ to } 105 \text{ °C}, t < 1 \text{ s}$,	_	_	350	Ω
		I_{ON} = 10 mA, I_F = 10 mA, T_a = -40 to 125° C, t < 1 s	_	_	400	



10. Isolation Characteristics ($T_a = 25$ °C)

Characteristics	Symbol	Note	Test Condition		Тур.	Max	Unit
Capacitance input to output Cs (Note1) Vs = 0 V, f = 1 MHz		_	0.9		pF		
Isolation resistance Rs (Note1) Vs = 1000V, R.H. ≤ 60 %		5×10 ¹⁰	10 ¹⁴		Ω		
Isolation voltage	BVs	(Note1)	AC, 60 s	5000	_	1	Vrms

Note1: Device considered a two-terminal device: Pins 1 to 6 shorted together, and 7 and 12 shorted together.

11. Switching Characteristics

Characteristics	Symbol	Note	Test Condition		Min	Тур.	Max	Unit
Turn on time	ton		I _F = 10 mA	T _a = 25 °C	_	_	1	
Turn off time	toff		$R_L = 20 \text{ k}\Omega$ $V_{DD} = 40 \text{ V}$		_	_	1	ms
Turn on time	ton		- VDD - 40 V	T _a = -40 to 125°C	_	_	1	
Turn off time	t _{OFF}				_	_	1	ms

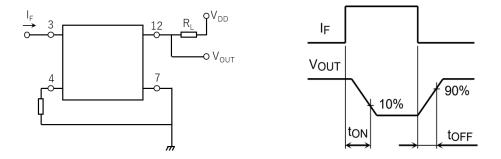


Fig. 11.1 Switching Time Test Circuit and Waveform



12. Characteristics Curves (Note)

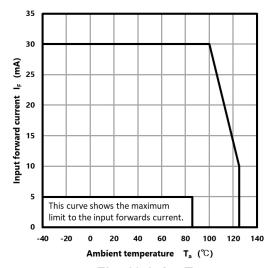


Fig. 12.1 I_F - T_a

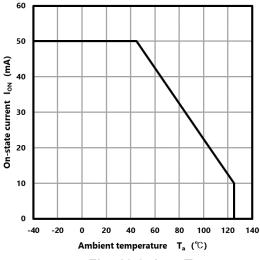


Fig. 12.2 I_{ON} - T_a

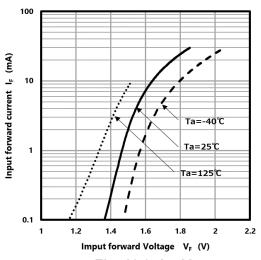


Fig. 12.3 I_F - V_F

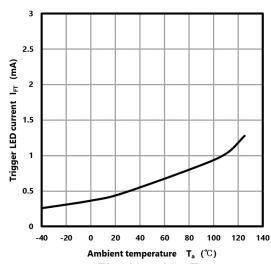


Fig. 12.4 I_{FT} - T_a

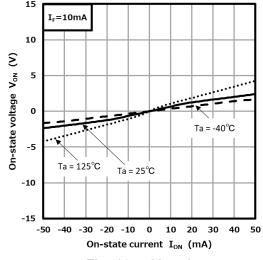


Fig. 12.5 Von - Ion

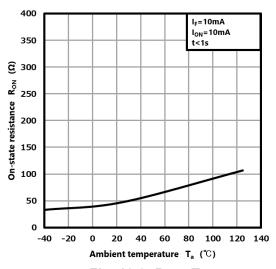


Fig. 12.6 R_{ON} - T_a



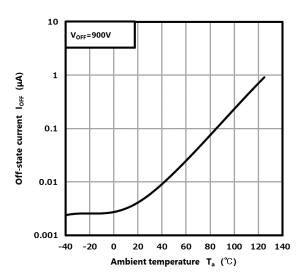


Fig. 12.7 I_{OFF} - T_a

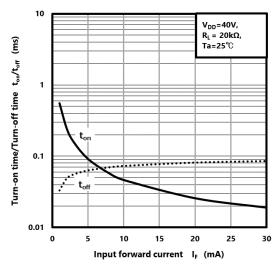


Fig. 12.8 t_{ON}/t_{OFF} - I_F

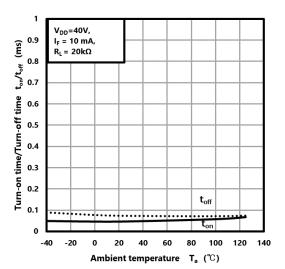


Fig. 12.9 ton/toff - Ta

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



13. Package Dimensions

Unit: mm 7.76 ± 0.2 **►** A 12 7 В 10 ± 0.2 6 2 3 1 1.27 ± 0.15 10 ± 0.2 <u>\$</u> 0.5 Min ___ 0.1 S

Weight: 0.31 g (typ.)

Package Name(s)
TOSHIBA: 11-8C1A



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